## NSN 5962-01-065-9891

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View Online at https://aerobasegroup.com/nsn/5962-01-065-9891 **Body Length:** Between 0.755 inches and 0.790 inches **Body Width:** Between 0.265 inches and 0.300 inches **Body Height:** Between 0.155 inches and 0.175 inches **Maximum Power Dissipation Rating:** 650.0 milliwatts **Operating Tempurature Range:** +0.0/+75.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Radar set type an/fps-115 **Features Provided:** Hermetically sealed and monolithic and positive outputs and w/storage and programmable and programmed and w/open collector and bipolar and w/enable and w/decoded output **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 5.5 volts power source **Time Rating Per Chacteristic:** 30.00 nanoseconds propagation delay time, low to high level output and 30.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Test Data Document:** 04761-640-200061 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 

Demilitarization: Voc. domil/mli

**Unit Of Measure:** 

16 printed circuit Shelf Life:

N/a

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